Preferred Device

JFET VHF/UHF Amplifier Transistor

N-Channel

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	30	Vdc
Drain-Gate Voltage	V_{DG}	30	Vdc
Gate-Source Voltage	V _{GS}	30	Vdc
Gate Current	IG	10	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

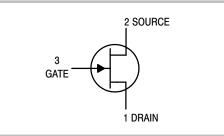
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.



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SOT-23 (TO-236) CASE 318 STYLE 10

MARKING DIAGRAM



M6A = Device Code M = Date Code* ■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBF4416LT1	SOT-23	3,000 / Tape & Reel
MMBF4416LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Gate–Source Breakdown Voltage ($I_G = 1.0 \mu Adc, V_{DS} = 0$)		V _{(BR)GSS}	30	-	Vdc
Gate Reverse Current $(V_{GS} = 20 \text{ Vdc}, V_{DS} = 0)$ $(V_{GS} = 20 \text{ Vdc}, V_{DS} = 0, T_A = 0)$	50°C)	I _{GSS}	_ _	1.0 200	nAdc
Gate Source Cutoff Voltage (I _D = 1.0 nAdc, V _{DS} = 15 Vdc)			-	-6.0	Vdc
Gate Source Voltage (I _D = 0.5 mAdc, V _{DS} = 15 Vdc)			-1.0	-5.5	Vdc
ON CHARACTERISTICS					
Zero-Gate-Voltage Drain Current (V _{GS} = 15 Vdc, V _{GS} = 0)			5.0	15	mAdc
Gate-Source Forward Voltage (I _G = 1.0 mAdc, V _{DS} = 0)			-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS			•	•	•
Forward Transfer Admittance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1.0 kHz)			4500	7500	μmhos
Output Admittance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1.0 kHz)			-	50	μmhos
Input Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1.0 MHz)			-	4.0	pF
Reverse Transfer Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 10 MHz)			-	0.8	pF
Output Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1.0 MHz)			_	2.0	pF

COMMON SOURCE CHARACTERISTICS ADMITTANCE PARAMETERS

 $(V_{DS} = 15 \text{ Vdc}, T_{channel} = 25^{\circ}C)$

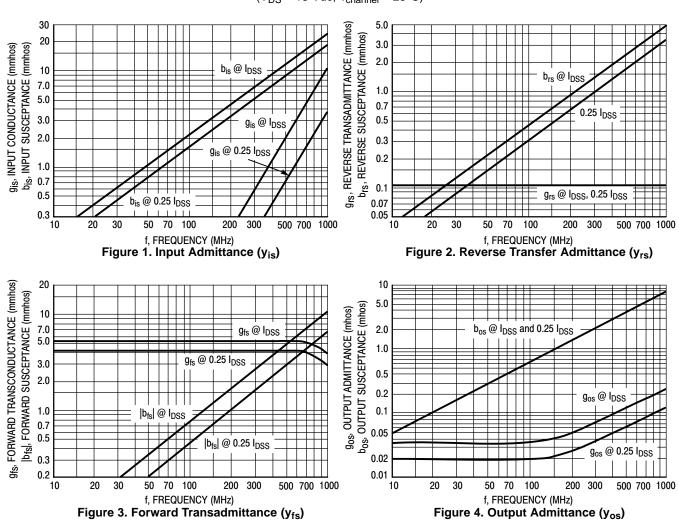


Figure 3. Forward Transadmittance (y_{fs})

COMMON SOURCE CHARACTERISTICS S-PARAMETERS

(V_{DS} = 15 Vdc, T_{channel} = 25°C, Data Points in MHz) 340° $I_{D} = 0.25 I_{DSS}$ 1.0 40° 320° 0.4 320° 0.9 50° 310° 310° $I_{D} = I_{DSS}, 0.25 I_{DSS}$ 800 0.2 $I_D = I_{DSS}$ 60° 300° 60° 300° 700 0.1 0.7 70° 70° 290° 290° 400 280° 80° 809 2809 0.0 900 270° 90 270° 90° 100° 260° 100° 260° 110° 250° 110 250° 120° 240° 120 240° 130° 130° 230° 230° 220° 140° 220° 140° 160° Figure 6. S_{12s} Figure 5. S_{11s} 330° 350° 340° 1.0 200 300 40° 320° 320° 0.6 50 310° 50° 310° $I_D = I_{DSS}$ 0.8 0.5 60° 300° 60° 300° 70° 290° 70° 290° 809 280° 80° 280° 90° 270° 90 270° 100° 100° 260° 260° 110° 110° 250° 250° 240° 120° 240° 0.5 130° 230° 130° 230° 0.6 140° 140° 220°

Figure 8. S_{22s}

Figure 7. S_{21s}

COMMON GATE CHARACTERISTICS ADMITTANCE PARAMETERS

 $(V_{DG} = 15 \text{ Vdc}, T_{channel} = 25^{\circ}C)$

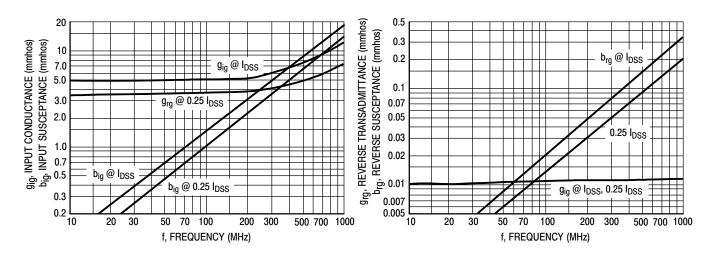


Figure 9. Input Admittance (yig)

Figure 10. Reverse Transfer Admittance (y_{rg})

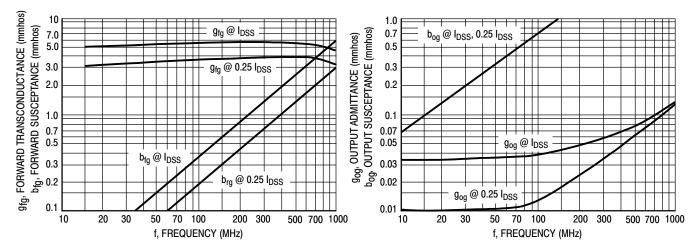


Figure 11. Forward Transfer Admittance (yfg)

Figure 12. Output Admittance (yoq)

COMMON GATE CHARACTERISTICS S-PARAMETERS

(V_{DS} = 15 Vdc, T_{channel} = 25°C, Data Points in MHz)

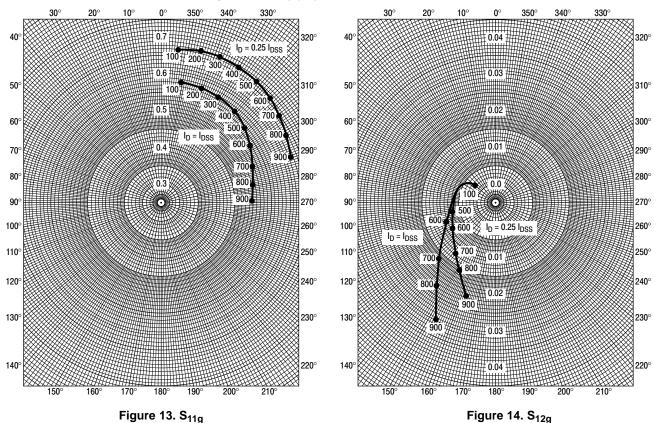


Figure 13. S_{11g}

Figure 15. S_{21g}

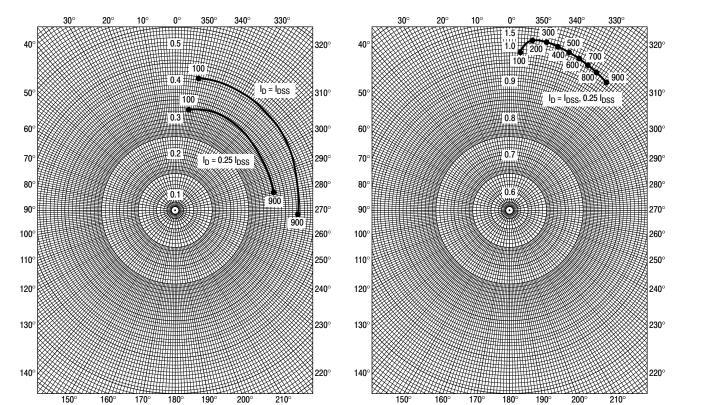


Figure 16. S_{22g}

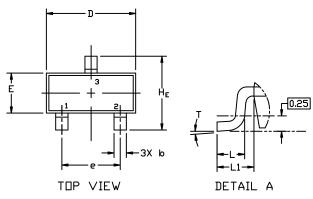


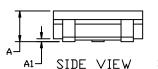


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DATE 01 MAR 2023









NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		INCHES			
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Ε	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10°	0*		10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	1	
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE	STYLE 19: N PIN 1. CATHODE 2. ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 24: PIN 1. GATE 2. DRAIN 3. SOURCE	STYLE 25: PIN 1. ANODE 2. CATHODE 3. GATE	STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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